

	L #	Hits	Search Text	DBs
1	L1	383161	"257"/\$.ccls. "438"/\$.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
2	L2	23496	1 and (interconnect? or damascene)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
3	L3	72	2 and (poison\$3 near photoresist)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
4	L4	14	3 and (nitrogen near doped) near (SiC or (silicon near carbide))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
5	L6	9	4 and (oxygen near doped) near (SiC or (silicon near carbide))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
6	L7	9	6 and (etch-stop or (etch enar stop))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
7	L8	9	7 and cap	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
8	L9	187	(xu-ping or xia-li-qun or dworkin-larry-a).in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
9	L10	11	9 and (poison\$3 near photoresist)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
10	L12	6	10 and ((nitrogen and oxygen) near doped) near (SiC or (silicon near carbide))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
11	L13	23	(poison\$3 near photoresist).ti.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
12	L14	126	(nitrogen near doped) near (SiC or (silicon near carbide))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
13	L15	45	14 and (oxygen near doped) near (SiC or (silicon near carbide))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
14	L16	32	15 and (etch-stop or (etch near stop))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
15	L17	1	15 and ((nitrogen near doped) near (SiC or (silicon near carbide)) near (etch near stop))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB